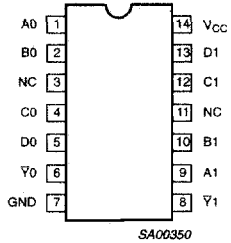
3.3V Dual 4-input NAND gate | 74LVT20

QUICK REFERENCE DATA

SYMBOL	PARAMETER	CONDITIONS T_{amb} = 25°C; GND = 0V	TYPICAL	UNIT
t_{PLH} t_{PHL}	Propagation delay An, Bn, Cn, Dn to $\overline{Y}n$	C_L = 50pF; V_{CC} = 3.3V	3.4 3.2	ns
C_{IN}	Input capacitance	V_I = 0V or 3.0V	3	pF
I_{CCL}	Total supply current	Outputs Low; V_{CC} = 3.6V	0.5	mA

PIN CONFIGURATION



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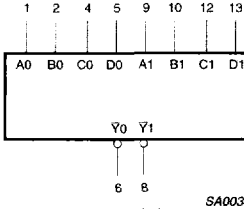
PIN DESCRIPTION

PIN NUMBER	SYMBOL	NAME AND FUNCTION
1, 2, 4, 5, 9, 10, 12, 13	An, Bn, Cn, Dn	Data inputs
6, 8	$\overline{Y}n$	Data outputs
7	GND	Ground (0V)
14	V_{CC}	Positive supply voltage

LOGIC SYMBOL



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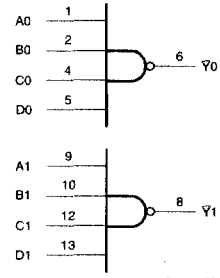
LOGIC DIAGRAM



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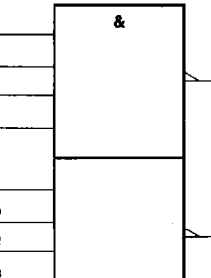
LOGIC SYMBOL (IEEE/IEC)



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FUNCTION TABLE

INPUTS				OUTPUT
Dna	Dnb	Dnc	Dnd	$\overline{Q}n$
L	X	X	X	H
X	L	X	X	H
X	X	L	X	H
X	X	X	L	H
H	H	H	H	L

NOTES:
H = High voltage level
L = Low voltage level
X = Don't care

ORDERING INFORMATION

PACKAGES	TEMPERATURE RANGE	OUTSIDE NORTH AMERICA	NORTH AMERICA	DWG NUMBER
14-Pin Plastic SO	–40°C to +85°C	74LVT20 D	74LVT20 D	SOT108-1
14-Pin Plastic SSOP	–40°C to +85°C	74LVT20 DB	74LVT20 DB	SOT337-1
14-Pin Plastic TSSOP	–40°C to +85°C	74LVT20 PW	74LVT20PW DH	SOT402-1

ABSOLUTE MAXIMUM RATINGS[1, 2]

SYMBOL	PARAMETER	CONDITIONS	RATING	UNIT
V_{CC}	DC supply voltage		−0.5 to +4.6	V
I_{IK}	DC input diode current	$V_I < 0$	−50	mA
V_I	DC input voltage[3]		−0.5 to +7.0	V
I_{OK}	DC output diode current	$V_O < 0$	−50	mA
V_{OUT}	DC output voltage[3]	Output in Off or High state	−0.5 to +7.0	V
I_{OUT}	DC output current	Output in High state	−32	mA
		Output in Low state	64	
T_{stg}	Storage temperature range		−65 to 150	°C

NOTES:
1. Stresses beyond those listed may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
2. The performance capability of a high-performance integrated circuit in conjunction with its thermal environment can create junction temperatures which are detrimental to reliability. The maximum junction temperature of this integrated circuit should not exceed 150°C.
3. The input and output negative voltage ratings may be exceeded if the input and output clamp current ratings are observed.

RECOMMENDED OPERATING CONDITIONS

SYMBOL	PARAMETER	LIMITS		UNIT
		MIN	MAX	
V_{CC}	DC supply voltage	2.7	3.6	V
V_I	Input voltage	0	5.5	V
V_{IH}	High-level input voltage	2.0		V
V_{IL}	Low-level input voltage		0.8	V
I_{OH}	High-level output current		−20	mA
I_{OL}	Low-level output current		32	mA
	Low-level output current; current duty cycle ≤ 50%, f ≥ 1kHz		48	
T_{amb}	Operating free-air temperature range	−40	+85	°C

DC ELECTRICAL CHARACTERISTICS

Over recommended operating conditions
Voltages are referenced to GND (ground = 0V)

SYMBOL	PARAMETER	TEST CONDITIONS	LIMITS			UNIT
			Temp = -40°C to +85°C			
			MIN	TYP[1]	MAX	
V_{IK}	Input clamp voltage	V_{CC} = 2.7V; I_{IK} = –18mA			–1.2	V
V_{OH}	High-level output voltage	V_{CC} = 2.7 to 3.6V; I_{OH} = –100µA	V_{CC}–0.2			V
		V_{CC} = 2.7V; I_{OH} = –6mA	2.4			
		V_{CC} = 3.0V; I_{OH} = –20mA	2.0			
V_{OL}	Low-level output voltage	V_{CC} = 2.7V; I_{OL} = 100µA			0.2	V
		V_{CC} = 2.7V; I_{OL} = 24mA			0.5	
		V_{CC} = 3.0V; I_{OL} = 32mA			0.5	
I_I	Input leakage current	V_{CC} = 0 or 3.6V; V_I = 5.5V			10	µA
		V_{CC} = 3.6V; V_I = V_{CC} or GND			±1	
I_{OFF}	Output off current	V_{CC} = 0V; V_I or V_O = 0 to 4.5V			±100	µA
I_{CCH}	Quiescent supply current	V_{CC} = 3.6V; Outputs High, V_I = GND or V_{CC}, I_O = 0			0.02	mA
I_{CCL}		V_{CC} = 3.6V; Outputs Low, V_I = GND or V_{CC}, I_O = 0		0.5	1.2	
ΔI_{CC}	Additional supply current per input pin[2]	V_{CC} = 3V to 3.6V; One input at V_{CC}–0.6V, Other inputs at V_{CC} or GND			0.2	µA
C_I	Input capacitance	V_I = 3V or 0		3		pF

NOTES:
1. All typical values are at V_{CC} = 3.3V and T_{amb} = 25°C.
2. This is the increase in supply current for each input at the specificed voltage level other than V_{CC} or GND.

AC CHARACTERISTICS

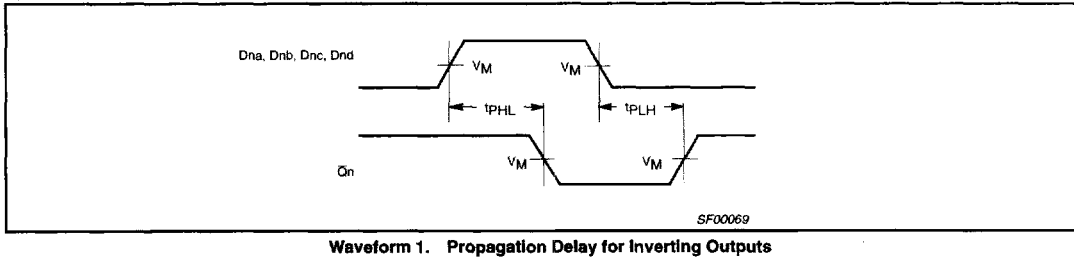
GND = 0V; $t_R = t_F$ = 2.5ns; C_L = 50pF, R_L = 500Ω; T_{amb} = –40°C to +85°C.

SYMBOL	PARAMETER	WAVEFORM	LIMITS				UNIT
			V_{CC} = 3.3V ± 0.3V			V_{CC} = 2.7V	
			MIN	TYP[1]	MAX	MAX	
t_{PLH} t_{PHL}	Propagation delay An, Bn, Cn, Dn to $\overline{Y}$n	1	1.0 1.0	3.4 3.2	5.4 4.4	6.4 4.3	ns

NOTE:
1. All typical values are at V_{CC} = 3.3V and T_{amb} = 25°C.

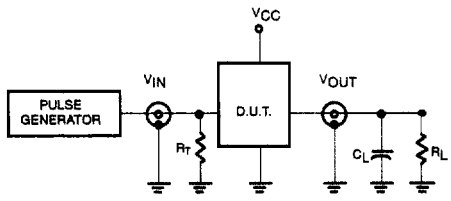
AC WAVEFORMS

V_M = 1.5V, V_{IN} = GND to 2.7V

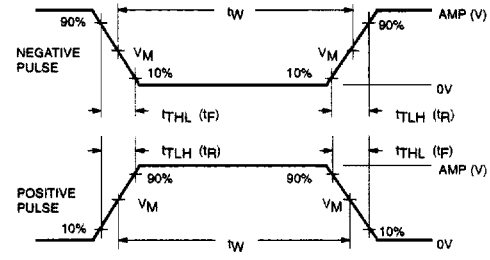


Waveform 1. Propagation Delay for Inverting Outputs

TEST CIRCUIT AND WAVEFORMS



Test Circuit for Outputs



V_M = 1.5V
Input Pulse Definition

DEFINITIONS

R_L = Load resistor; see AC CHARACTERISTICS for value.

C_L = Load capacitance includes jig and probe capacitance; see AC CHARACTERISTICS for value.

R_T = Termination resistance should be equal to Z_{OUT} of pulse generators.

FAMILY	INPUT PULSE REQUIREMENTS				
	Amplitude	Rep. Rate	t_W	t_R	t_F
74LVT	2.7V	≤10MHz	500ns	≤2.5ns	≤2.5ns

SV00022